TEXAS INSTRUMENTS

**TMAG5253**
ZHCSPM0B – MAY 2023 – REVISED NOVEMBER 2023

# TMAG5253 采用超小型封装且具有 EN 引脚的低功耗线性霍尔效应传感器

## 1 特性

- 业界先进的低功耗：
  - 电源电压，$V_{CC}$：1.65V - 3.6V
  - 关断电流：< 20nA（25°C 时为 1.8V）
  - 有效电流：2mA（25°C 时为 1.8V）
  - 平均电流：100Hz 占空比时 < 10μA
- 专用使能引脚
- 快速开通时间：< 25μs
- 比例式模拟输出与 $V_{CC}$ 成比例
- 关断模式下的高阻抗输出
- 低噪声输出，具有 ±1mA 的驱动能力
- 支持正负磁场的双极灵敏度选项
- 磁性灵敏度范围选项：
  - A1：±20mT 范围
  - A2：±40mT 范围
  - A3：±80mT 范围
  - A4：±160mT 范围
- 支持钕磁铁温漂的灵敏度补偿
- 超小型 X2SON 4 引脚封装：1.54 mm²
- 宽工作温度范围：‑40°C 至 125°C

## 2 应用

- 游戏控制器和外设
- 磁接近传感器
- 移动机器人电机控制
- 无线电动工具
- 扫地机器人
- 无人机有效载荷控制

## 3 说明

TMAG5253 是一款低功耗线性霍尔效应传感器，可按比例响应磁通量密度。该器件具有使能引脚，可进入超低功耗 (nA) 关断模式。TMAG5253 的启动时间很短 (< 25μs)，专为低功耗位置检测应用而设计。该器件采用业界出色的 1.54mm² 超小型封装，适用于空间狭小的应用。该器件具有宽电源电压范围，可在 1.65V 至 3.6V 电压范围内运行。

垂直于封装顶部的磁通量由器件感应，并且 TMAG5253 提供双极灵敏度极性选项，其中北磁极和南磁极会产生不同的输出电压。输出会随施加的磁通量密度呈线性变化，四个灵敏度选项可以根据所需的感应范围提供最大的输出电压摆幅。
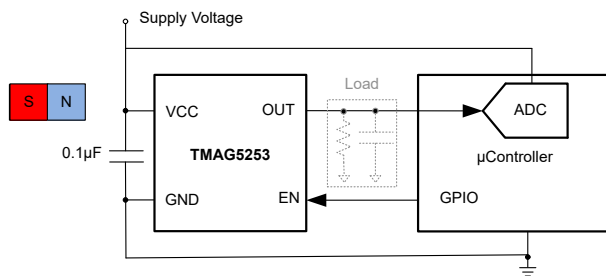
该器件使用比例式架构，当外部模数转换器 (ADC) 使用相同的 $V_{CC}$ 作为其基准电压时，可消除 $V_{CC}$ 容差产生的误差。此外，该器件还具有磁体温度补偿功能，可抵消 -40°C 至 125°C 宽温度范围内的磁灵敏度漂移。该器件还能够在关断模式下将输出置于高阻抗状态。这使得多个器件能够连接到单个 ADC。

### 封装信息[1]

| 器件型号 | 封装 | 封装尺寸[2] |
| --- | --- | --- |
| TMAG5253 | DMR (X2SON.4) | 1.40mm × 1.10mm |

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

(2) 封装尺寸（长 x 宽）为标称值，并包括引脚（如适用）。



典型电路原理图

English Data Sheet: SBASAI5

# Table of Contents

Product Folder Links: *TMAG5253*

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## 4 Device Comparison

表 4-1. Device Comparison

| ORDERABLE | MAGNETIC RESPONSE TYPE | MINIMUM LINEAR MAGNETIC SENSING RANGE (mT) | TYPICAL SENSITIVITY TEMPERATURE COEFFICIENT (%/°C) |
|---|---|---|---|
| TMAG5253BA1 | Bipolar | ±20 | 0.12 |
| TMAG5253BA2 | Bipolar | ±40 | 0.12 |
| TMAG5253BA3 | Bipolar | ±80 | 0.12 |
| TMAG5253BA4 | Bipolar | ±160 | 0.12 |

## 5 Pin Configuration and Functions
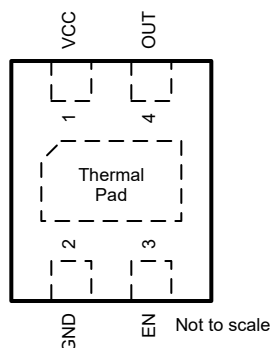


图 5-1. DMR Package 4-Pin X2SON Top View

表 5-1. Pin Functions

| PIN | | TYPE[1] | DESCRIPTION |
|---|---|---|---|
| NAME | X2SON | | |
| $V_{CC}$ | 1 | P | Power supply. TI recommends connecting this pin to a ceramic capacitor to ground with a value of at least 0.1 µF. |
| GND | 2 | G | Ground reference |
| EN | 3 | I | Enable pin |
| OUT | 4 | O | Analog output |
| Thermal Pad | 5 | NC | No connect. This pin should be left floating or tied to ground. The pin should be soldered to the board for mechanical support. |

(1)     I = Input, O = Output, I/O = Input and Output, G = Ground, P = Power, NC = No Connect

# 6 Specifications

## 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

| | | MIN | MAX | UNIT |
|---|---|---|---|---|
| Power supply voltage | $V_{CC}$ | $-0.3$ | 5.5 | V |
| Output voltage | OUT | $-0.3$ | $V_{CC} + 0.3$ | V |
| Magnetic flux density, $B_{MAX}$ | | Unlimited | | T |
| Operating junction temperature, $T_J$ | | $-40$ | 125 | °C |
| Storage temperature, $T_{stg}$ | | $-65$ | 150 | °C |

(1) Operation outside theAbsolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

## 6.2 ESD Ratings

| | | | VALUE | UNIT |
|---|---|---|---|---|
| $V_{(ESD)}$ | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001[1] | ±2000 | V |
| | | Charged-device model (CDM), per JEDEC specification ANSI/ESDA/JEDEC JS-002[2] | ±750 | |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|---|---|---|---|---|
| $V_{CC}$ | Power supply voltage[1] | 1.65 | 3.6 | V |
| $C_L$ | Load capacitance on OUT pin | | 1 | nF |
| $I_O$ | Output continuous current | $-1$ | 1 | mA |
| $T_A$ | Operating ambient temperature[2] | $-40$ | 125 | °C |

(1) These are recommended supply ranges. For more details refer to *Operating Vcc Ranges* section
(2) Power dissipation and thermal limits must be observed.

## 6.4 Thermal Information

| THERMAL METRIC[1] | | TMAG5253 | UNIT |
|---|---|---|---|
| | | DMR(X2SON) | |
| | | 4 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 157.1 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 110.9 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 105 | °C/W |
| $Y_{JT}$ | Junction-to-top characterization parameter | 2.4 | °C/W |
| $Y_{JB}$ | Junction-to-board characterization parameter | 101.9 | °C/W |
| $R_{\theta JC(bot)}$ | Junction-to-board (bottom) thermal resistance | 85.7 | °C/W |

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

## 6.5 Electrical Characteristics

for $V_{CC}$ = 1.65 V to 3.6 V, over operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS[1] | | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|---|
| $I_{CC\_ACTIVE}$ | Operating supply current | EN > $V_{IH}$ | VCC = 1.8 V | | 2 | 3.3 | mA |
| | | | VCC = 3.3 V | | 2.6 | 5 | |
| $I_{CC\_SHDN}$ | Shutdown current | VCC = 3.3 V, EN < $V_{IL}$ | | | 8 | | nA |
| $t_{ON}$ | Power-on time | VCC > VCC(min) | | | 20 | 45 | µs |
| $VCC_{ramp}$ | VCC ramp rate | T = 25 C | | 0.001 | | 1 | V / µs |
| $V_{IH}$ | Input high voltage for EN pin | | | $0.65 \times V_{CC}$ | | | V |
| $V_{IL}$ | Input low voltage for EN pin | | | | | $0.35 \times V_{CC}$ | V |
| $V_{hys}$ | Input hysteresis voltage for EN pin | | | $0.1 \times V_{CC}$ | | | V |
| $f_{BW}$ | Sensing bandwidth ( -3 dB) | Rload = 100 KΩ, Cload=100 pF | | | 15 | | kHz |
| $R_{OUT}$ | DC output resistance | EN > $V_{IH}$ | | | 1.27 | | Ω |
| $R_{OUT}$ | DC output resistance | EN < $V_{IL}$ | | | 9 | | MΩ |

(1)  B is the applied magnetic flux density.

## 6.6 Magnetic Characteristics

for $V_{CC}$ = 1.65 V to 3.6 V, over operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS[1] | | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|---|
| $V_Q$ | Quiescent voltage | B = 0 mT, $T_A$ = 25°C | $V_{CC}$ = 3.3 V, TMAG5253BA1 | 1.585 | 1.65 | 1.715 | V |
| | | | $V_{CC}$ = 3.3 V, TMAG5253BA2 | 1.585 | 1.65 | 1.715 | V |
| | | | $V_{CC}$ = 3.3 V, TMAG5253BA3 | 1.585 | 1.65 | 1.715 | V |
| | | | $V_{CC}$ = 3.3 V, TMAG5253BA4 | 1.585 | 1.65 | 1.715 | V |
| | | | $V_{CC}$ = 1.8 V, TMAG5253BA1 | 0.845 | 0.9 | 0.945 | |
| | | | $V_{CC}$ = 1.8 V, TMAG5253BA2 | 0.845 | 0.9 | 0.945 | V |
| | | | $V_{CC}$ = 1.8 V, TMAG5253BA3 | 0.845 | 0.9 | 0.945 | V |
| | | | $V_{CC}$ = 1.8 V, TMAG5253BA4 | 0.845 | 0.9 | 0.945 | V |
| $V_{Q\Delta T}$ | Quiescent voltage temperature drift | B = 0 mT | $V_{CC}$ = 3.3 V, $T_A$ = 0°C to 85°C versus 25°C , TMAG5253B | -60 | | 60 | mV |
| | | | $V_{CC}$ = 3.3 V, $T_A$ = -40°C to 125°C versus 25°C , TMAG5253B | -100 | | 100 | mV |
| | | | $V_{CC}$ = 1.8 V, $T_A$ = 0°C to 85°C versus 25°C , TMAG5253B | -30 | | 30 | mV |
| | | | $V_{CC}$ = 1.8 V, $T_A$ = -40°C to 125°C versus 25°C , TMAG5253B | -50 | | 50 | mV |
| $V_{QRE}$ | Quiescent voltage ratiometry error[2] | TMAG5253B | | | ±0.2 | | % |
| $V_{Q\Delta L}$ | Quiescent voltage lifetime drift | $V_{CC}$ = 3.3 V, High-temperature operating stress for 1000 hours | | | 10 | | mV |

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Product Folder Links: *TMAG5253*

English Data Sheet: SBASAI5

for $V_{CC}$ = 1.65 V to 3.6 V, over operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS[1] | | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|---|
| S | Sensitivity | $V_{CC}$ = 3.3 V, $T_A$ = 25°C | TMAG5253BA1 | 51 | 60 | 69 | mV/mT |
| | | | TMAG5253BA2 | 25.5 | 30 | 34.5 | |
| | | | TMAG5253BA3 | 12.75 | 15 | 17.25 | |
| | | | TMAG5253BA4 | 6.37 | 7.5 | 8.62 | |
| | | $V_{CC}$ = 1.8 V, $T_A$ = 25°C | TMAG5253BA1 | 25.5 | 30 | 34.5 | |
| | | | TMAG5253BA2 | 13.6 | 16 | 18.4 | |
| | | | TMAG5253BA3 | 6.9 | 8.12 | 9.33 | |
| | | | TMAG5253BA4 | 3 | 3.5 | 4.0 | |
| $B_L$ | Linear magnetic sensing range[3] [4] | $V_{CC}$ = 3.3 V, $T_A$ = 25°C | TMAG5253BA1 | ±20 | | | mT |
| | | | TMAG5253BA2 | ±40 | | | |
| | | | TMAG5253BA3 | ±80 | | | |
| | | | TMAG5253BA4 | ±160 | | | |
| | | $V_{CC}$ = 1.8 V, $T_A$ = 25°C | TMAG5253BA1 | ±20 | | | |
| | | | TMAG5253BA2 | ±40 | | | |
| | | | TMAG5253BA3 | ±80 | | | |
| | | | TMAG5253BA4 | ±160 | | | |
| $V_L$ | Linear range of output voltage[4] | TMAG5253B | | 0.2 | | $V_{CC}$ – 0.2 | V |
| $S_{TC}$ | Sensitivity temperature coefficient[5] | TA = -40°C to 125°C versus 25°C | TMAG5253BA | 0.04 | 0.12 | 0.2 | %/°C |
| $S_{LE}$ | Sensitivity linearity error[4] | $V_{OUT}$ is within $V_L$ | | | ±0.1 | ±0.55 | % |
| $S_{SE}$ | Sensitivity symmetry error[4] | $V_{OUT}$ is within $V_L$ | TMAG5253B | | ±0.1 | | % |
| $S_{RE}$ | Sensitivity ratiometry error[2] | $T_A$ = 25°C, $V_{CC}$ = 1.65 V -1.9 V , with respect to $V_{CC}$ = 1.8V | | – 2 | | 2 | % |
| | | $T_A$ = 25°C, $V_{CC}$ = 3 V - 3.6 V , with respect to VCC = 3.3 V | | – 3 | | 3 | % |
| $S_{\Delta L}$ | Sensitivity lifetime drift | High-temperature operating stress for 1000 hours | | | 0.5 | | % |
| $B_{ND}$ | Input-referred RMS noise density | $V_{CC}$ = 3.3 V , Cload=100 pF | | | 220 | | nT/√Hz |
| | | $V_{CC}$ = 1.8V , Cload=100 pF | | | 400 | | |
| $B_N$ | Input-referred peak-to-peak noise | $B_{ND}$ × 6.6 × √$f_{BW}$ , Cload = 100 pF | $V_{CC}$ = 3.3 V | | 0.17 | | mT$_{PP}$ |
| | | | $V_{CC}$ = 1.8 V | | 0.35 | | |
| $V_N$ | Output-referred peak-to-peak noise | $B_N$ × S , VCC=3.3 V, BW = 15 kHz | TMAG5253BA1 | | 9.2 | | mV$_{PP}$ |
| | | | TMAG5253BA2 | | 4.6 | | |
| | | | TMAG5253BA3 | | 2.3 | | |
| | | | TMAG5253BA4 | | 1.2 | | |

(1)    B is the applied magnetic flux density.
(2)    Refer to the *Ratiometric Architecture* section
(3)    $B_L$ describes the minimum linear sensing range at 25°C taking into account the maximum $V_Q$ and Sensitivity tolerances.
(4)    Refer to the *Sensitivity Linearity* section
(5)    $S_{TC}$ describes the rate the device increases Sensitivity with temperature. For more information, see the *Magnetic Response* section.

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## 6.7 Typical Characteristics

$T_A$ = 25°C (unless otherwise noted)



V$_{CC}$ = 3.3 V

图 6-1. TMAG5253BA1 Sensitivity Linearity Error vs Magnetic Field



V$_{CC}$ = 3.3 V

图 6-2. TMAG5253BA2 Sensitivity Linearity Error vs Magnetic Field



V$_{CC}$ = 3.3 V
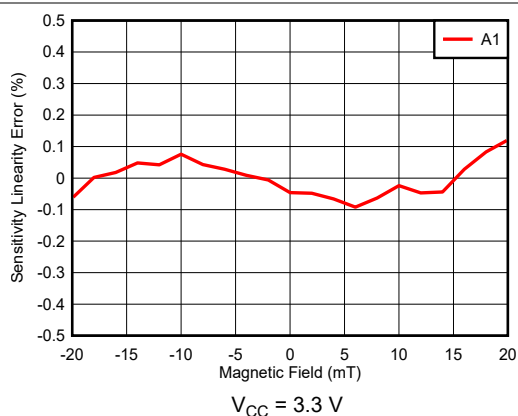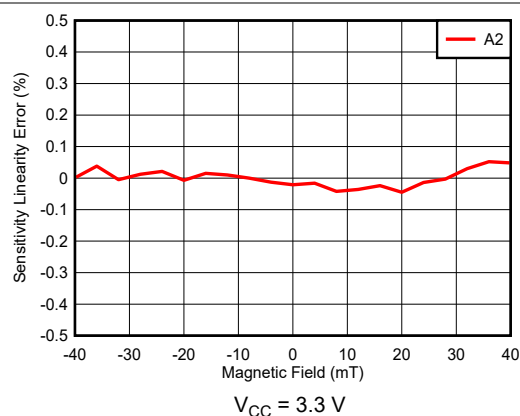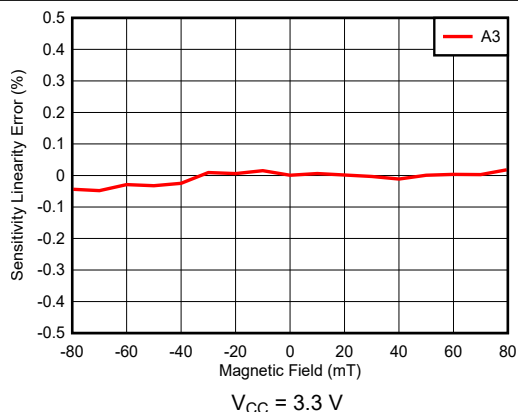
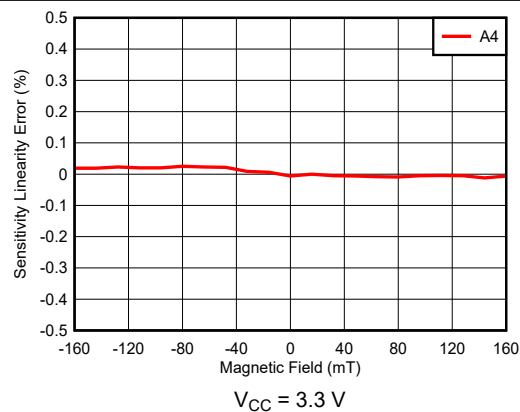图 6-3. TMAG5253BA3 Sensitivity Linearity Error vs Magnetic Field



V$_{CC}$ = 3.3 V

图 6-4. TMAG5253BA4 Sensitivity Linearity Error vs Magnetic Field
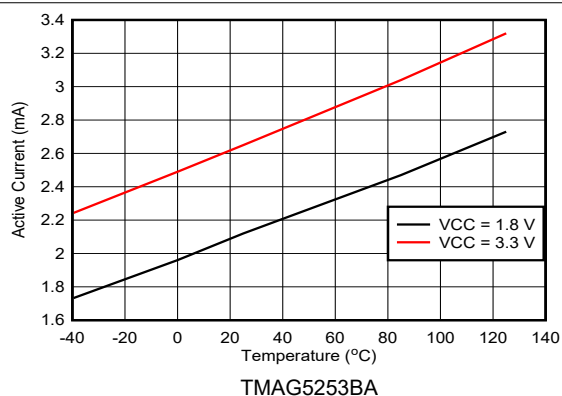


TMAG5253BA

图 6-5. TMAG5253BA Active Current vs Temperature



TMAG5253BA

图 6-6. TMAG5253BA Quiescent Voltage vs Supply Voltage

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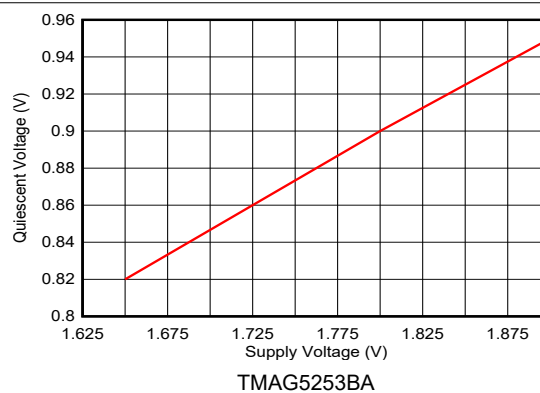
## 6.7 Typical Characteristics (continued)

$T_A$ = 25°C (unless otherwise noted)
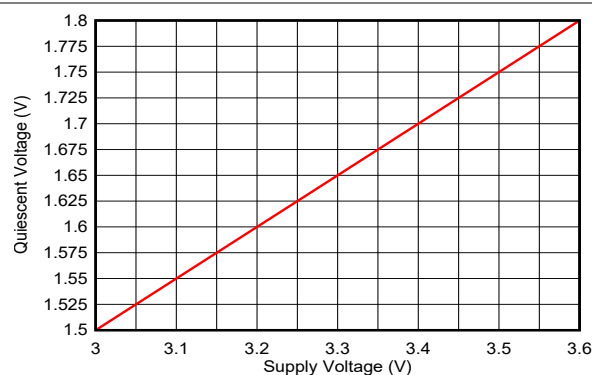


图 6-7. TMAG5253BA Quiescent Voltage vs Supply Voltage



$V_{CC}$ = 1.8 V
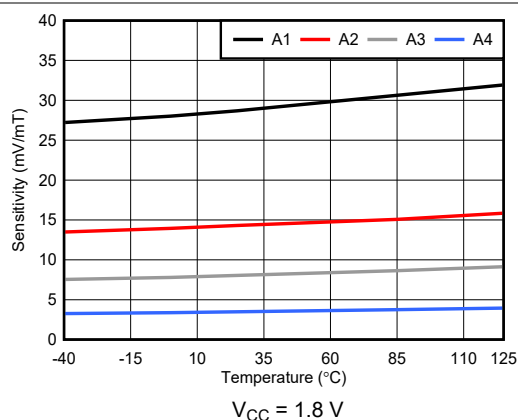
图 6-8. TMAG5253BA Sensitivity vs Temperature



$V_{CC}$ = 3.3 V
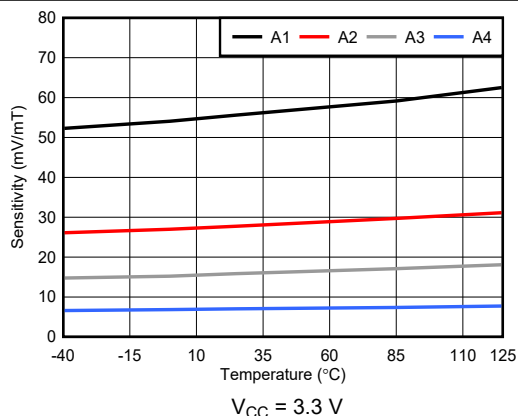
图 6-9. TMAG5253BA Sensitivity vs Temperature



$V_{CC}$ = 1.8 V ±10%
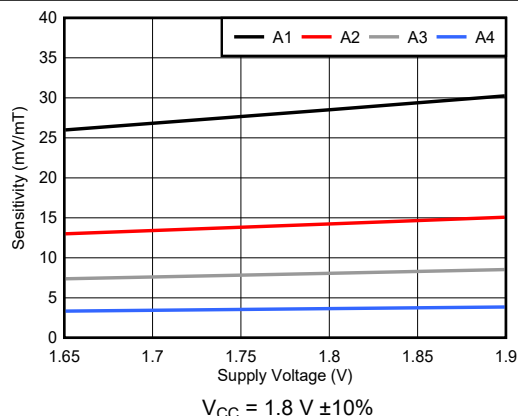
图 6-10. TMAG5253BA Sensitivity vs Supply Voltage



$V_{CC}$ = 3.3V ±10%
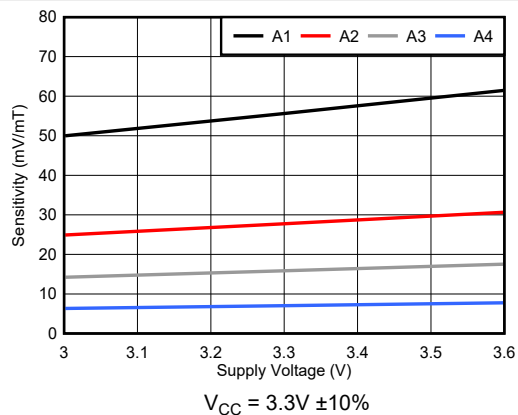
图 6-11. TMAG5253BA Sensitivity vs Supply Voltage
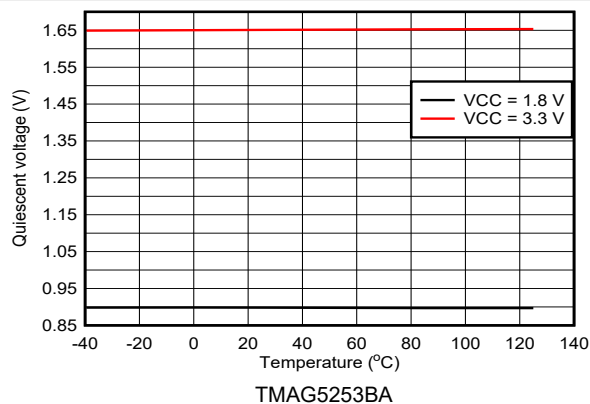


TMAG5253BA

图 6-12. TMAG5253BA Quiescent Voltage vs Temperature

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## 7 Parameter Measurement Information

### 7.1 Sensitivity Linearity

The device produces a linear response when the output voltage is within the specified $V_L$ range. Outside this range, sensitivity is reduced and nonlinear. 图 7-1 shows the linearity of the magnetic response for bipolar version.
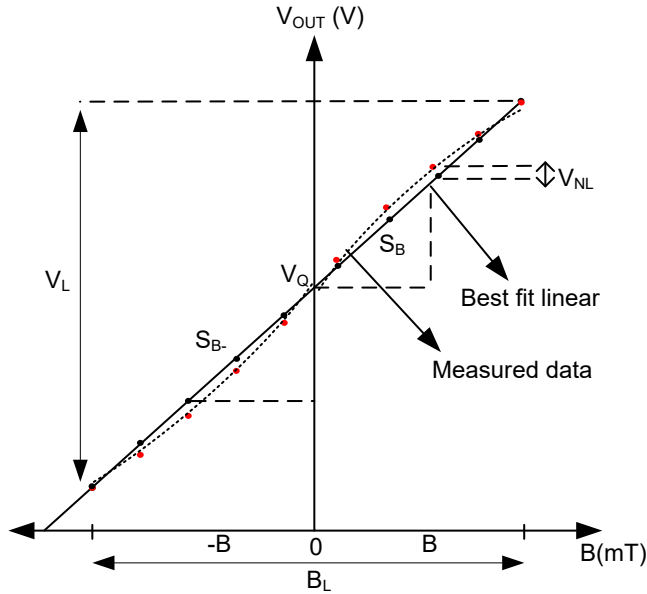


图 **7-1. Linearity of the Magnetic Response (Bipolar)**

方程式 1 calculates parameter $B_L$, the minimum linear sensing range at 25°C, and takes the maximum quiescent voltage and sensitivity tolerance into account.

$$B_{L(MIN)} = \frac{V_{L(MAX)} - V_{Q(MAX)}}{S_{(MAX)}} \tag{1}$$

Nonlinearity is the deviation of the output voltage from a linear relationship to the input current. Nonlinearity voltage, as shown in 图 7-1, is the maximum voltage deviation from the best-fit line based on measured parameters (see 方程式 2).

$$V_{NL} = V_{OUT} - \left(B_{IN} \times S_{FIT} + V_Q\right) \tag{2}$$

where

- $V_{OUT}$ is the voltage output at maximum deviation from best fit
- $B_{IN}$ is the magnetic flux density at maximum deviation from best fit
- $S_{FIT}$ is the best fit sensitivity of the device
- $V_Q$ is quiescent voltage at zero magnetic field = $V_{CC}/2$

The parameter $S_{LE}$, Sensitivity Linearity error is the nonlinearity voltage ,$V_{NL}$ specified as a percentage of the full-scale linear output range ($V_{FS}$) shown in 方程式 3.

$$S_{LE} = \left(\frac{V_{NL}}{V_{FS}}\right) \times 100\% \tag{3}$$

The parameter $S_{SE}$ defines symmetry error as the difference in sensitivity between any positive B value, $S_B$ and the negative B value of the same magnitude, $S_{-B}$ while the output voltage is within the $V_L$ range. This error only applies to the bipolar device option. Use 方程式 4 to calculate the symmetry error.

$$S_{SE} = \left( \frac{S_B - S_{-B}}{0.5 \times (S_B + S_{-B})} \right) \times 100\%$$

(4)

where

- $S_B$ refers to the sensitivity at a positive field B
- $S_{-B}$ refers to the sensitivity at a negative field B

## 7.2 Ratiometric Architecture

The TMAG5253 has a ratiometric analog architecture that scales the quiescent voltage and sensitivity linearly with the power-supply voltage. For example, the quiescent voltage and sensitivity are 5% higher when $V_{CC}$ = 3.465 V compared to $V_{CC}$ = 3.3 V. This ratiometric behavior enables an external ADC to digitize a consistent value regardless of the power-supply voltage tolerance when the ADC uses $V_{CC}$ as its reference.
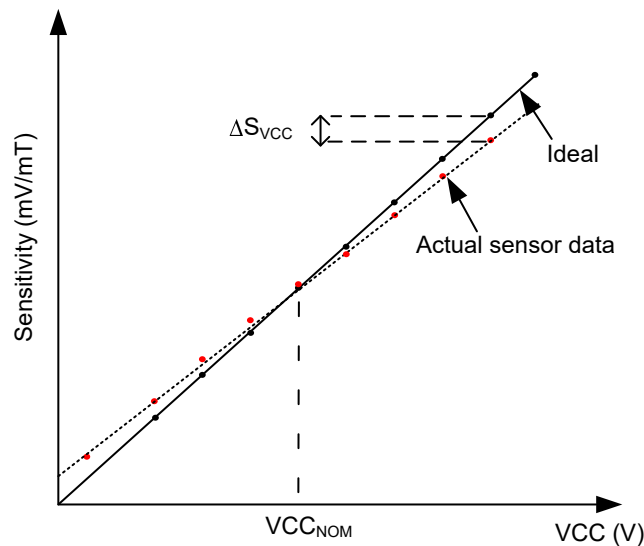


图 **7-2. Sensitivity Ratiometry Error**

Use 方程式 5 to calculate the sensitivity ratiometry error:

$$S_{RE} = \left( 1 - \frac{S_{VCC}/S_{VCC, NOM}}{V_{VCC}/V_{VCC, NOM}} \right) \times 100\%$$

(5)

where

- $S_{(VCC)}$ is the sensitivity at the current $V_{CC}$ voltage
- $S_{(NOM)}$ is the sensitivity at a nominal $V_{CC}$ voltage
- $V_{VCC}$ is the current $V_{CC}$ voltage
- $V_{VCC,NOM}$ is the nominal $V_{CC}$ voltage that is 1.8 V or 3.3 V

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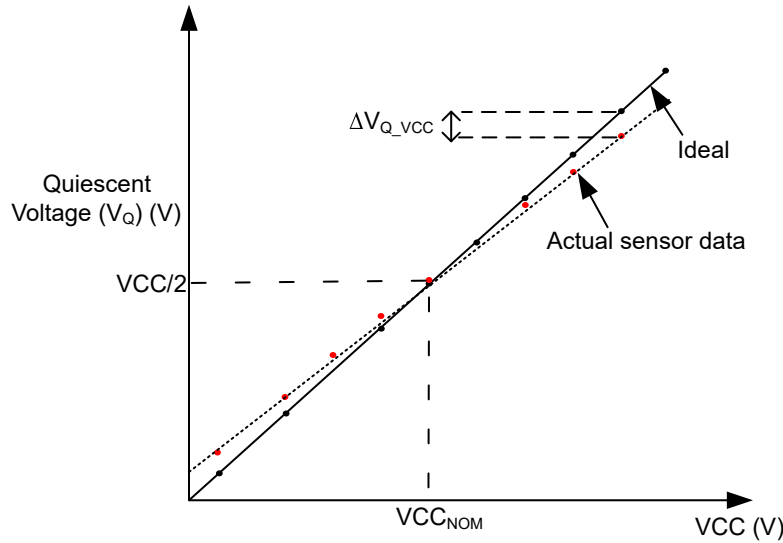
图 **7-3. Quiescent Ratiometry Error**

The TMAG5253 has a ratiometric architecture for the quiescent voltage of the bipolar device option. For the bipolar device option, at 0 mT, the quiescent voltage is typically half of the supply voltage, $V_{CC}$. Use 方程式 6 to calculate the quiescent voltage ratiometry error:

$$Q_{RE} = \left( 1 - \frac{V_{Q(VCC)}/V_{Q(NOM)}}{V_{VCC}/V_{VCC,NOM}} \right) \times 100\% \tag{6}$$

where

- $V_{Q(VCC)}$ is the quiescent voltage at the current $V_{CC}$ voltage
- $V_{Q(NOM)}$ is the quiescent voltage at a nominal $V_{CC}$ voltage
- $V_{CC}$ is the current $V_{CC}$ voltage
- $V_{VCC,NOM}$ is the nominal $V_{CC}$ voltage that is 1.8 V or 3.3 V

## 7.3 Sensitivity Temperature Compensation

Magnets generally produce weaker fields as temperature increases. Different types of magnets have different sensitivity temperature coefficients. The TMAG5253 compensates by increasing sensitivity with temperature, as defined by the parameter $S_{TC}$. Use 方程式 7 and 方程式 8 to calculate the sensitivity at a fixed supply voltage.

$$\text{Sensitivity} = \text{Sensitivity}_{25°C} \times \left( 1 + S_{TC} \times (T_A - 25°C) \right) \tag{7}$$

$$S_{TC} = \frac{100}{\text{Gain at 25°C}} \times \frac{\text{Gain at Temp} - \text{Gain at 25°C}}{\text{Temp} - 25} \tag{8}$$

where

- $\text{Sensitivity}_{(25°C)}$ depends on the polarity (unipolar/bipolar) and the four different device options (1, 2, 3, 4)
- $S_{TC}$ is the Sensitivity temperature coefficient
- $T_A$ is the ambient temperature

Product Folder Links: *TMAG5253*

English Data Sheet: SBASAI5

## 7.4 Quiescent Voltage Temperature Drift

Quiescent voltage temperature drift is defined in the Magnetic Characteristic section. This can be calculated using the following equation:

$$VQ\Delta T = VQ_{(VCC)} \text{ at } 25°C - VQ_{(VCC)} \text{ at Temp} \tag{9}$$

where

- $V_{Q(VCC)}$ is the quiescent voltage at the current $V_{CC}$ voltage

## 7.5 Power-On Time

After the $V_{CC}$ voltage is applied, the TMAG5253 requires a short initialization time before the output settles to its final value. The parameter $T_{ON}$ describes the time from when $V_{CC}$ crosses $V_{CC(MIN)}$ until OUT is within 5% of the final value, with a constant magnetic field and a typical load of 100 pF from OUT to ground. 图 7-4 shows this timing diagram.



**图 7-4. $T_{ON}$ for $V_{CC}$ Ramp**

$T_{ON}$ is also used to describe the time from when EN pin is pulled above $V_{IH}$ until OUT is within 5% of the final value, with a constant magnetic field and a typical load of 100 pF from OUT to ground. 图 7-4 shows this timing diagram.
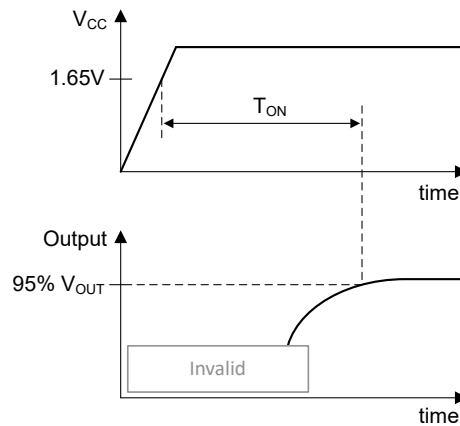


**图 7-5. $T_{ON}$ When Using EN Pin**

Product Folder Links: *TMAG5253*

English Data Sheet: SBASAI5
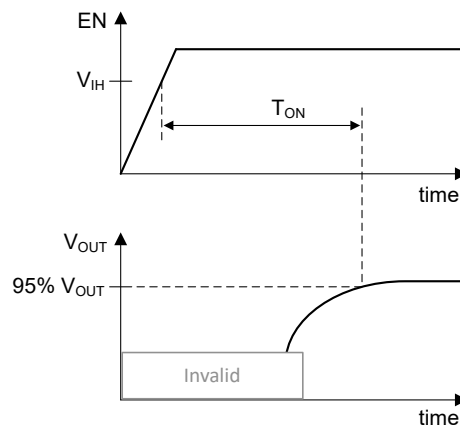
# 8 Detailed Description

## 8.1 Overview

The TMAG5253 is a 4-pin, low-power linear Hall effect sensor with fully integrated signal conditioning, temperature compensation circuits, mechanical stress cancellation, and output driver. The device supports wide supply range and can operate on 1.8-V or 3.3-V power supplies, measures magnetic flux density, and outputs a proportional analog voltage that is referenced to $V_{CC}$. The device also features an enable pin that is used to place the device in a ultra-low power (nA) mode when needed.

The device is offered in bipolar magnetic response version that is sensitive to both the north and the south pole. TMAG5253 is also offered in 4 different sensitivity versions (±20 mT, ±40 mT, ±80 mT, or ±160 mT). This allows the user to trade off sensitivity range and resolution to support low cost magnet selections or wider range wherever it is needed.

The device is offered in magnetic temperature coefficient of 0.12%/°C to compensate for magnetic sensitivity temperature coefficient of Neodymium magnet type.

## 8.2 Functional Block Diagram
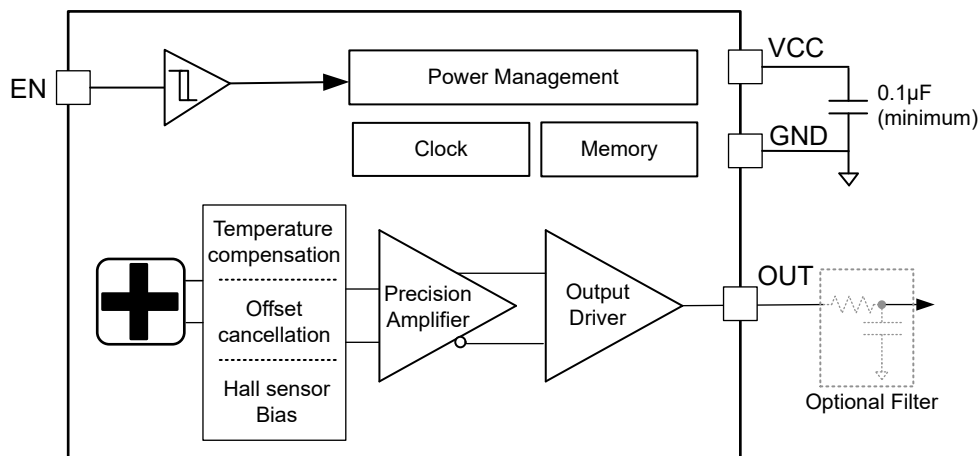


## 8.3 Feature Description

### 8.3.1 Magnetic Flux Direction

As shown in 图 8-1, the TMAG5253 is sensitive to the magnetic field component that is perpendicular to the top of the package.
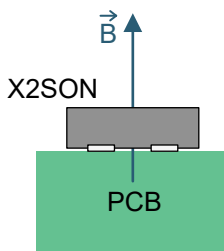


图 8-1. Direction of Sensitivity

Product Folder Links: *TMAG5253*

English Data Sheet: SBASAI5

Magnetic flux that travels from the bottom to the top of the package is considered positive in this document. This condition exists when a south magnetic pole is near the top (marked-side) of the package as shown in 图 8-2. Magnetic flux that travels from the top to the bottom of the package results in negative millitesla values.
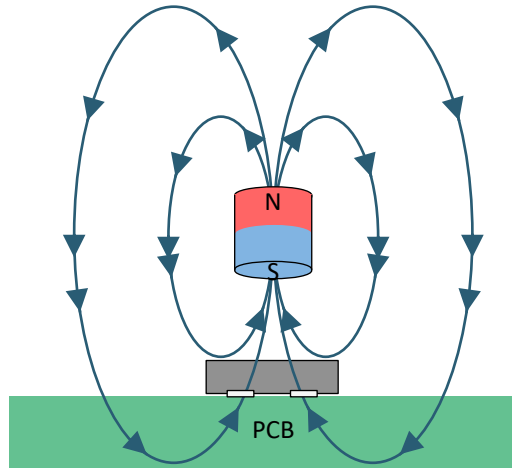


**图 8-2. The Flux Direction for Positive B**

### 8.3.2 Hall Element Location

图 8-3 shows the location of the sensing element inside each package option along with the tolerances.



**图 8-3. Hall Element Location**

Product Folder Links: *TMAG5253*

English Data Sheet: *SBASAI5*
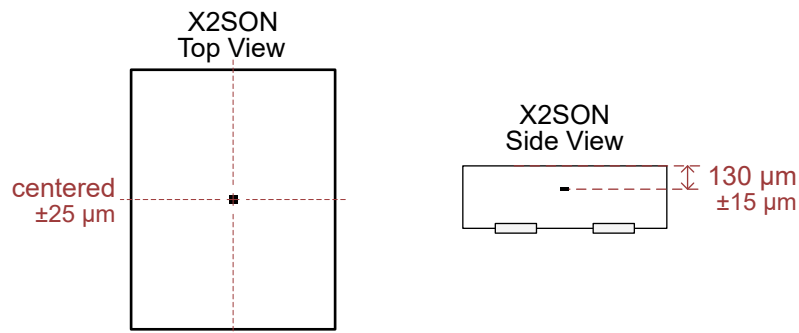
### 8.3.3 Magnetic Response

图 8-4 shows the response of the bipolar device option (B), which is sensitive to both the positive and negative magnetic fields.
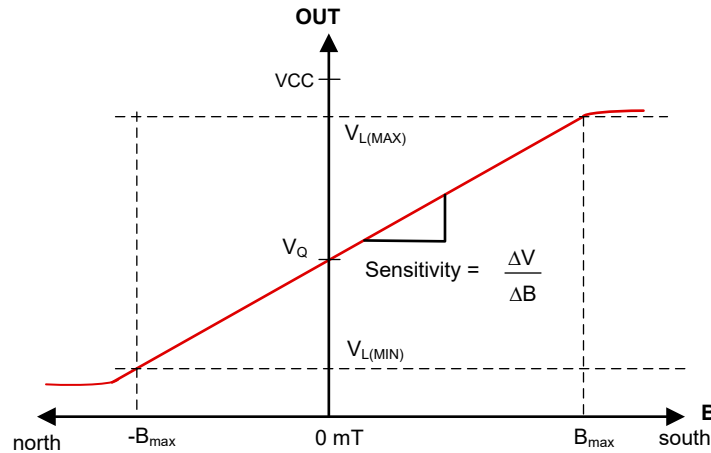


图 **8-4. Magnetic Response for TMAG5253B (Bipolar) Version**

At room temperature, use 方程式 10 to calculate the ideal first-order transfer function of the TMAG5253, where the output voltage is a linear function of the input magnetic field and the supply voltage.

$$V_{OUT} = V_Q + B \times \text{Sensitivity} \times \frac{V_{CC}}{V_{CC, NOM}}$$

(10)

where

- $V_Q$ is the quiescent output voltage for a field of 0 mT.

    - $V_Q = V_{CC}/2$ for Bipolar device option (B)
- B is the applied magnetic flux density
- Sensitivity refers to the magnetic sensitivity of the device
- $V_{OUT}$ is the analog output voltage within the $V_L$ range
- $V_{CC}$ refers to the supply voltage of the device
- $V_{CC,NOM}$ is the nominal supply voltage where the sensitivity is defined, such as 1.8 V or 3.3 V

As an example, consider the TMAG5253BA3, a bipolar magnetic response version with a sensitivity of 15 mV/mT at 3.3-V supply voltage and at room temperature. With $V_{CC}$ = 3.4 V and an input field of 67 mT, you can calculate the output voltage, $V_{OUT}$ for this example.

$$V_{OUT} = 1.7\,V + 67\,mT \times 0.015\,\frac{V}{mT} \times \frac{3.4\,V}{3.3\,V} = 2.735\,V$$

(11)

## 8.4 Device Functional Modes

The TMAG5253 has two modes of operations that apply when the *Recommended Operating Conditions* are met.

When the EN pin is connected to $V_{CC}$, the part enters active mode, where the OUT pin provides an analog output that corresponds to the magnetic sensitivity and the supply voltage.

When the EN pin is tied to GND, the TMAG5253 enters an ultra-low power shutdown mode that consumes only 20-nA current. During the shutdown mode, the OUT pin is driven to a high-impedance state.

## 9 Application and Implementation

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备注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

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### 9.1 Application Information

#### 9.1.1 Selecting the Sensitivity Option

Select the highest TMAG5253 sensitivity option that can measure the required range of magnetic flux density so that the output voltage swing is maximized.

Larger-sized magnets and farther sensing distances can generally enable better positional accuracy than very small magnets at close distances, because magnetic flux density increases exponentially with the proximity to a magnet. TI has developed online tools to provide assistance with magnetic field calculations that assist with magnet selections and the mechanical placement of the sensor for the most common use cases.

#### 9.1.2 Temperature Compensation for Magnets

The magnetic field of magnets based on Neodymium or the Ferrite magnets have a high temperature coefficient. The residual induction ($B_r$) of a magnet typically reduces by 0.12%/°C for NdFeB, and 0.20%/°C for ferrite material. The TMAG5253 features sensitivity temperature compensation that is designed to directly compensate the average drift of magnets. When the operating temperature range of a system is reduced, temperature drift errors are also reduced.

For device options A1 – A4, the sensitivity at $T_A$ = 125°C is typically 12% higher than at $T_A$ = 25°C. These device options are typically used when Neodymium magnets are used along with the TMAG5253. The device options B1 – B4 are recommended when using along with Ferrite magnets. For device options B1 – B4, the sensitivity at $T_A$ = 125°C is typically 20% higher than at $T_A$ = 25°C. For device options , Z1 – Z4, the sensitivity at $T_A$ = 125°C is typically same as the value at $T_A$ = 25°C. These options are typically used when measuring ambient currents or when the magnetic field does not vary with temperature.

#### 9.1.3 Adding a Low-Pass Filter

As shown in *Functional Block Diagram*, an RC low-pass filter can be added to the device output for the purpose of minimizing voltage noise when the full 15-kHz bandwidth is not needed. This output filter can improve the signal-to-noise ratio (SNR) but at the expense of additional latency based on the external filter time constants.

Product Folder Links: *TMAG5253*

### 9.1.4 Designing With Multiple Sensors

Some applications require multiple linear Hall sensors to detect position in different parts of the system. In those cases, the primary challenge would be the availability of multiple ADC that are required to digitize the information from the sensors. In cases where the sensor is placed remotely away from the microcontroller, this would also mean multiple output lines between the sensor and microcontroller.

With the ability to place the output in high-impedance state during shutdown mode, multiple TMAG5253s can share the analog output. This can minimize the system cost by using a single ADC. 图 9-1 shows two devices that share the same analog output, with their respective EN pins controlled by the microcontroller. A pulldown resistor can be used to pull the output to ground when both the devices are placed in shutdown mode.
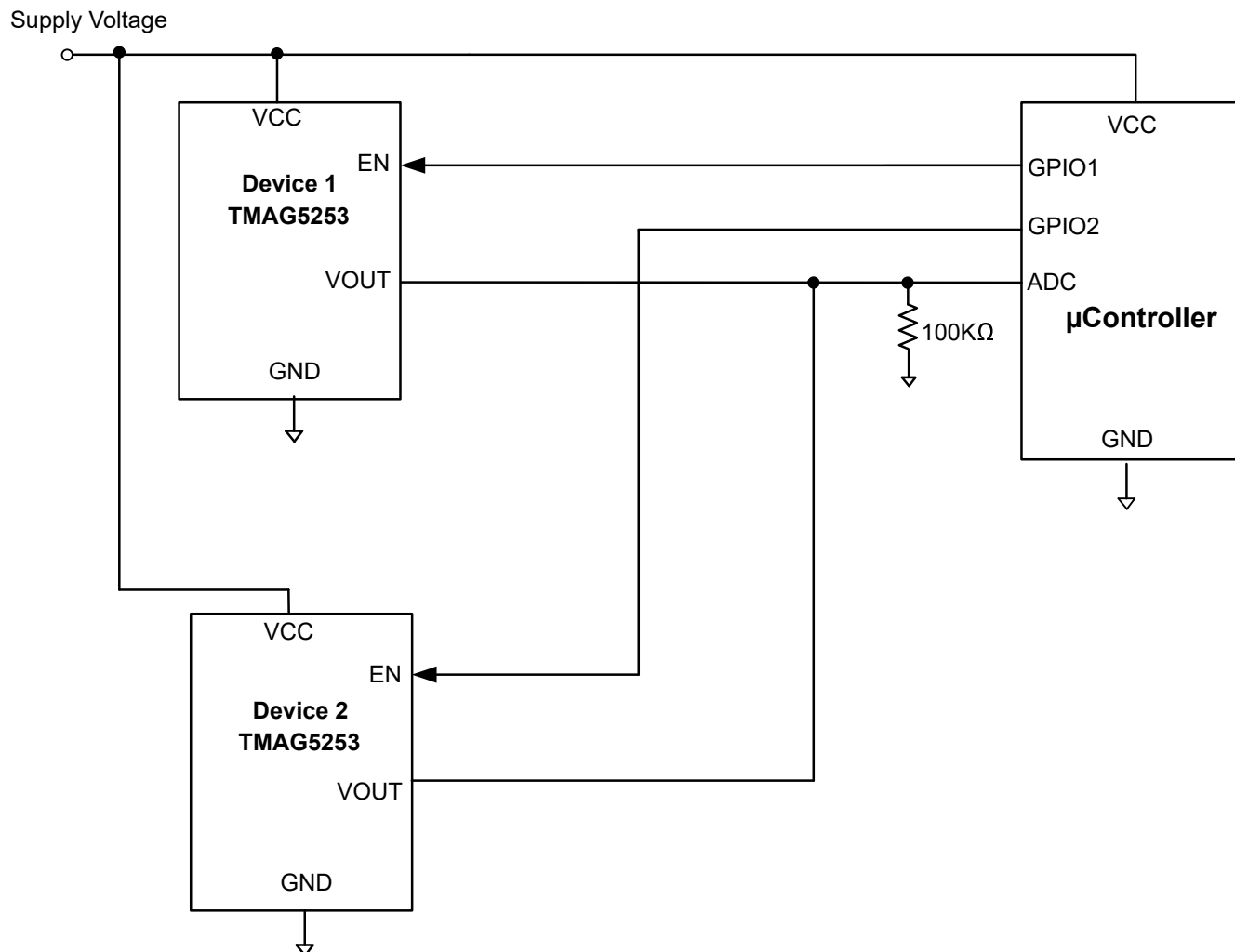


图 9-1. **Multiple Sensors With Shared Output**
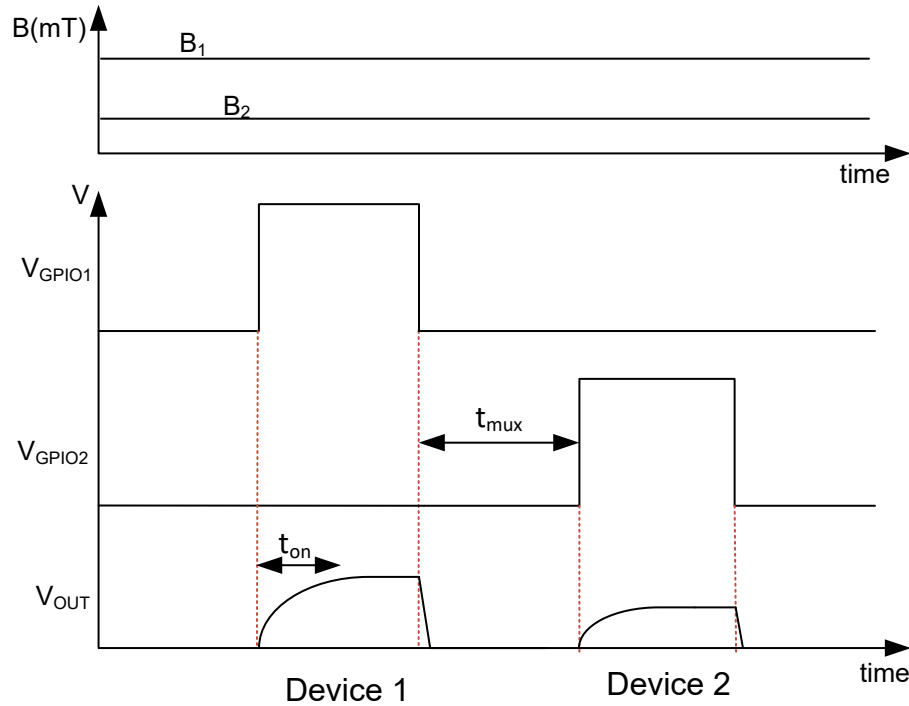
**图 9-2. Timing Diagram for Multiplexing the Sensor Outputs**

图 9-2 shows how the GPIOs of the microcontroller can be used to multiplex the outputs from the two sensors. When the GPIO1 goes high, Device 1 is enabled and drives the output line to the corresponding output after the power-on time. During this time, GPIO2 is driven low and Device 2 is placed in shutdown mode. When the output from the second device has to be measured, the first device must be turned off before the second device is enabled, indicated by $t_{mux}$ in the timing diagram. $B_1$ and $B_2$ correspond to the magnetic fields seen by Device 1 and Device 2, respectively.

With the ability to support up to 1-nF capacitive loads, the TMAG5253 enables multiple sensors to be connected to the same output. If the load capacitance on each sensor is about 20 pF, this would translate up to the ability of 50 sensors sharing the same output.

Product Folder Links: *TMAG5253*

English Data Sheet: SBASAI5

### 9.1.5 Duty-Cycled, Low-Power Design

For battery-powered applications where power is critical, the sensor can be duty-cycled using the EN pin. This will ensure the average current consumption remains low to meet the system level power targets. In duty-cycled applications, the start-up time must be very fast so the external ADC can sample the signal faster and shutdown the device quickly to minimize average power. With very fast start-up and power-off times, the TMAG5253 enables low average power consumption for the system.
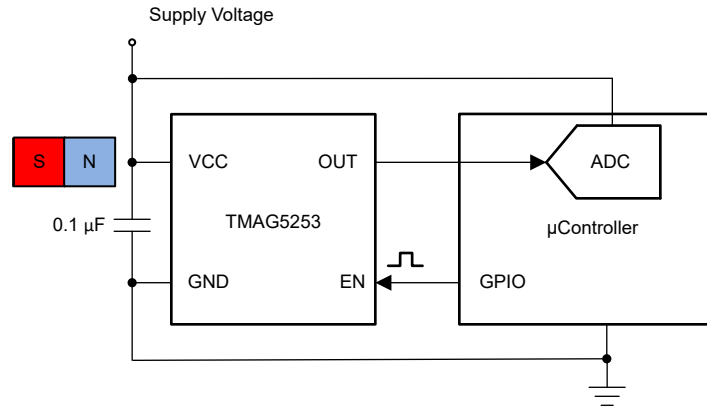


图 9-3. Typical Application Diagram for Duty-Cycled Application

图 9-3 shows the typical application diagram when the EN pin is controlled by the microcontroller. 图 9-4 shows the waveforms for this application where the EN pin is duty-cycled. The sampling time of the ADC should be scheduled after the output settles down to the required resolution. Notice that the output line is pulled down by the external resistor when EN is driven low. Also, if the input magnetic field is changed when the part is in shutdown, the device provides the new output corresponding to the field after the device enters active state.

Product Folder Links: TMAG5253

English Data Sheet: SBASAI5
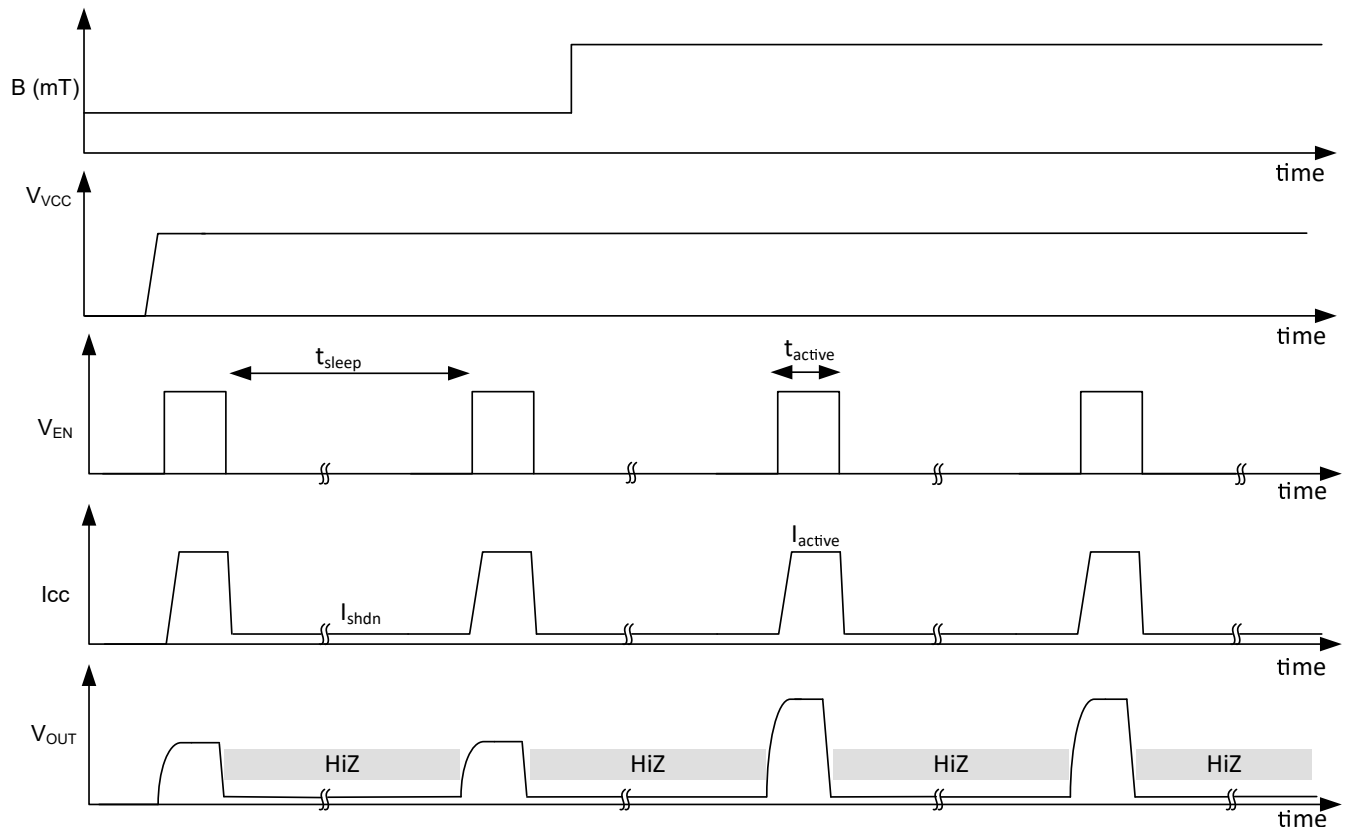
图 **9-4. Timing Diagram for Duty-Cycled Application**

表 9-1 shows the estimated average current consumption for the TMAG5253 versus the sleep time, for $V_{CC}$ = 1.8 V and the EN pin is tied high for 50 µs.

表 **9-1. Average Current Consumption**

| SLEEP TIME (ms) | AVERAGE CURRENT (µA) |
|---|---|
| 1 | 90.5 |
| 10 | 9.4 |
| 50 | 1.9 |
| 100 | 0.9 |
| 1000 | 0.1 |

## 9.2 Typical Applications

Magnetic 1D sensors are very popular due to contactless and reliable measurements, especially in applications requiring long-term measurements in rugged environments. The TMAG5253 offers design flexibility in a wide range of industrial and personal electronics applications, because many possible magnet orientations and movements produce a usable response from the sensor. In this section three common application examples are discussed in detail.

### 9.2.1 Slide-By Displacement Sensing

图 9-5 shows one of the most common orientations, which uses the full north to south range of the sensor and causes a close-to-linear change in magnetic flux density as the magnet moves across.

Product Folder Links: *TMAG5253*

English Data Sheet: *SBASAI5*
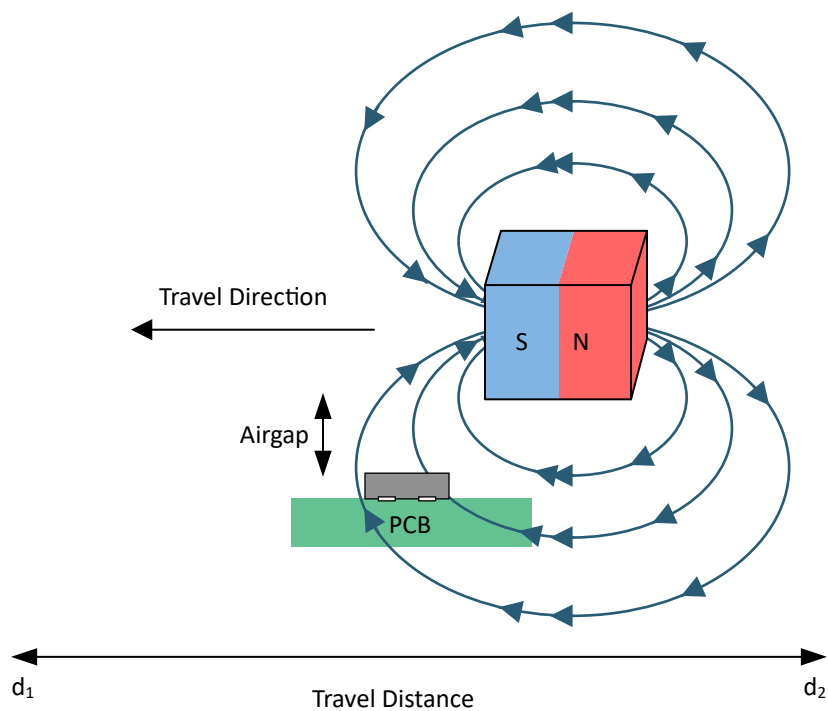
图 **9-5. Slide-By Sensing Magnet Orientation**

### 9.2.1.1 Design Requirements

Use the parameters listed in 表 9-2 for this design example.

**表 9-2. Design Parameters**

| DESIGN PARAMETER | EXAMPLE VALUE |
|---|---|
| $V_{CC}$ | 3.3 V |
| Magnet | 5 × 5 × 5 mm NdFeB (Grade N52) |
| Travel distance ($d_2$ – $d_1$) | 20 mm |
| Airgap | 3.0 mm (top of package to magnet) + 0.13 mm (distance from top of package to sensor location) |
| Maximum B at sensor at 25°C | ±80 mT |
| Device option | TMAG5253BA3 |

### 9.2.1.2 Detailed Design Procedure

When designing a linear magnetic sensing system, always consider these three variables: the magnet, sensing distance, and the range of the sensor. Notice from 图 9-5, the magnetic flux density versus distance has both positive and negative values as the magnet slides on top of the sensor. There is a region approximately the same length of the magnet which produces a linear change in field. To measure the magnetic flux density across the entire range, select the TMAG5253B version with the highest sensitivity that has a $B_L$ (linear magnetic sensing range) that is larger than the maximum magnetic flux density in the application. With this input, the user can monitor the change in position by measuring in the linear input region. 图 9-6 shows the magnetic flux density across the three axes in the sensor location. The sensor is sensitive only to the magnetic field on Z axis, and 图 9-7 shows the output voltage from the sensor, as the magnet slides on top of the sensor.

Notice that the linear region of sensing is only around ±3.0 mm, where the sensor output varies linearly with the position of the magnet. This linear range of operation will increase linearly with the size of the magnet. Based on the output voltage, it is determined that the sensor version with magnetic range of ±80 mT is able to cover the entire magnetic field range that is seen by the sensor. TI recommends using magnetic field simulation software and referring to magnet specifications and the mechanical placements to determine if the sensor with the right sensitivity.

### 9.2.1.3 Application Curves


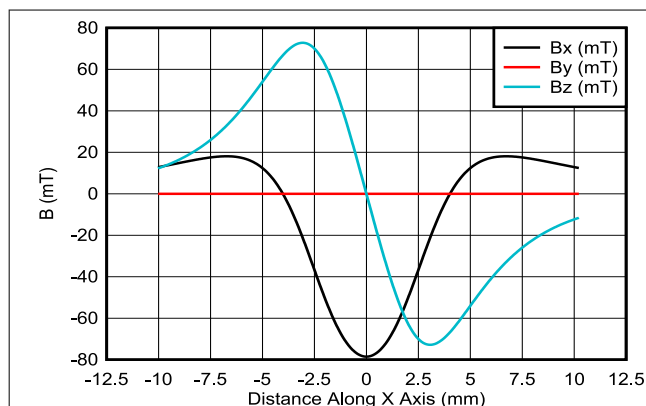
**图 9-6. Magnetic Field Across X, Y and Z Axes When The Magnet Slides by on Top of the Sensor**
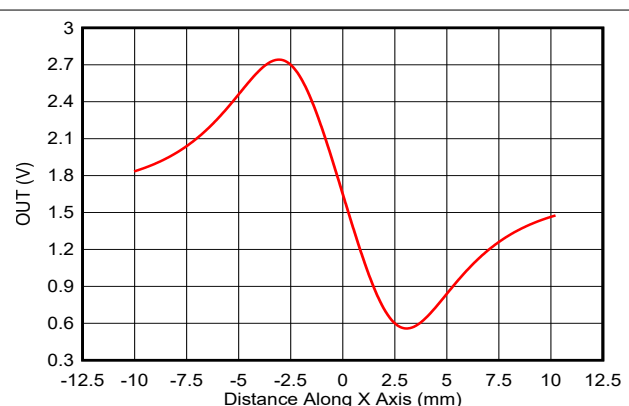


**图 9-7. Output Voltage of TMAG5253 When The Magnet Slides by on Top of the Sensor**

Product Folder Links: *TMAG5253*

English Data Sheet: SBASAI5

### 9.2.2 Head-On Displacement Sensing

图 9-8 shows another robust method for measuring linear position by using a magnet and the TMAG5253 in a head-on configuration. For this configuration, the linear axis of measurement of the Hall position sensor is along the path of travel, which results in a unique mapping of distance to magnetic flux density if the magnet is inline with the sensing axis of the Hall position sensor.
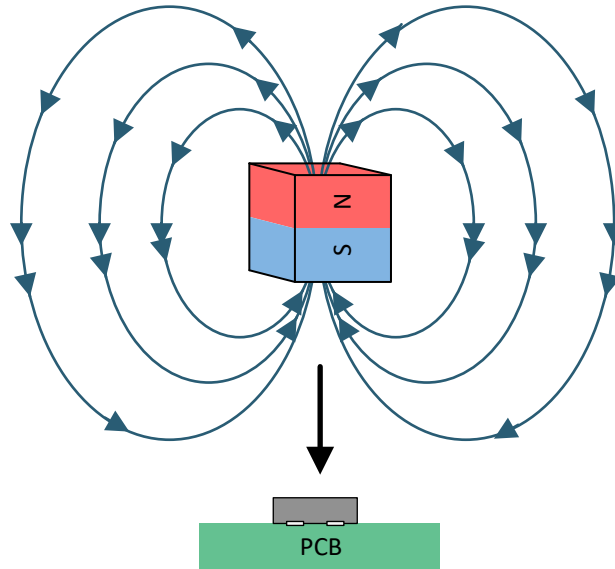


图 9-8. Head-On Displacement Sensing

#### 9.2.2.1 Design Requirements

Use the parameters listed in 表 9-3 for this design example.

表 9-3. Design Parameters

| DESIGN PARAMETER | EXAMPLE VALUE |
|---|---|
| $V_{CC}$ | 3.3 V |
| Magnet | 5 × 5 × 5 mm NdFeB N45 |
| Travel distance | 5 mm |
| Travel distance range from magnet to sensor surfaces | 10 mm to 5 mm |
| Magnetic field range at the sensor at 25°C | 80mT to 13 mT |
| Device option | TMAG5253BA3 |

#### 9.2.2.2 Detailed Design Procedure

Unlike the *Slide-By Displacement Sensing* configuration, the head-on displacement configuration has a magnetic flux density that is either entirely positive or entirely negative, depending on whether the south or north pole of the magnet is closest to the sensor. As a result, the user can choose the sensors that are sensitive only to south field for this mechanical configuration. In cases where it is not possible to control the polarity of the magnet, the bipolar version (TMAG5253B) is chosen. The mapping of magnetic flux density to distance depends on various factors, such as the material and dimensions of the magnet. 图 9-9 shows that the magnetic flux density is always positive as the magnet travels towards the sensor. Based on the magnetic field range, TMAG5253BA3 version with ±80 mT full scale range is chosen. 图 9-9 shows the output voltage of this sensor as the magnet travels from a distance of 10 mm to a distance of 5 mm towards the sensor. The DRV5056 Distance Measurement Tool calculates the expected magnetic flux density to distance mapping in a head-on configuration for different magnet specifications.

### 9.2.2.3 Application Curve
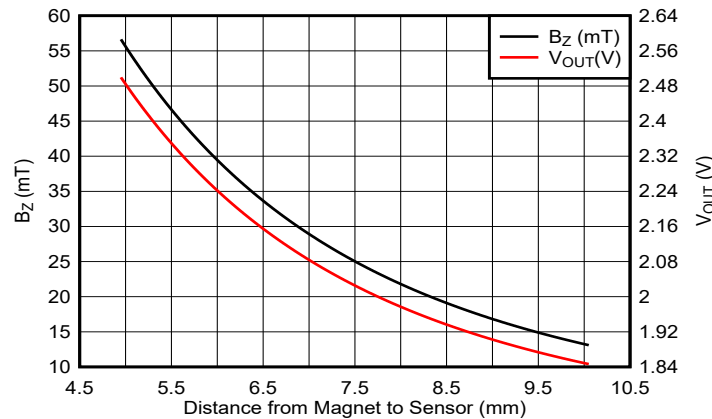


图 **9-9. Magnetic Field (B$_Z$) and the Output Voltage of the Sensor (V$_{OUT}$) vs the Distance from Magnet to the Sensor**

### 9.2.3 Remote-Sensing Applications

For remote-sensing applications where the sensor is not physically placed on the same board as the ADC or the microcontroller, it is important to have the ability to drive a capacitive load from the wiring harness. The TMAG5253 enables remote-sensing applications with the ability to support up to 1-nF capacitive load on the OUT pin. With a typical cable capacitance of about 100 pF/m, the TMAG5253 can support up to 10 m in cable length.
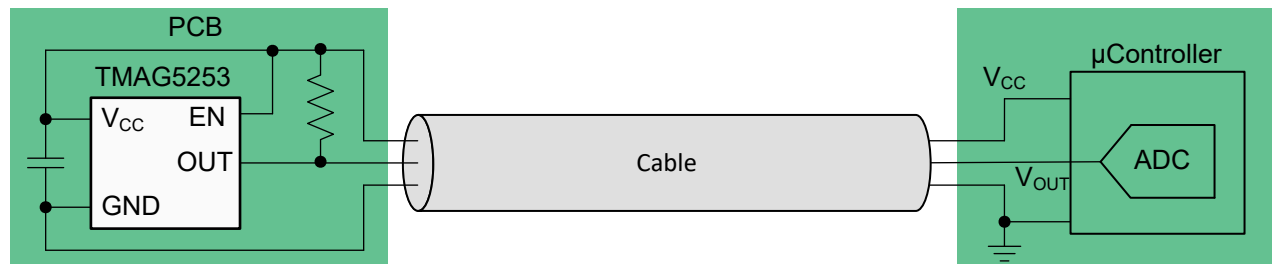


图 **9-10. Remote-Sensing Application With Wire Break Detection**

Some remote-sensing applications might require a device to detect if interconnect wires open or short. The TMAG5253 can support this feature with the ability to drive up to ±1-mA current load on the output. To design for wire break detection, first select a sensitivity option that causes the output voltage to stay within the V$_L$ range during normal operation. Second, add a pullup resistor between OUT and V$_{CC}$. TI recommends a value between 20 kΩ to 100 kΩ, and the current through OUT must not exceed the IO specification, including current going into an external ADC. Then, if the output voltage is ever measured to be within 100 mV of V$_{CC}$ or GND, a fault condition exists. 图 9-10 shows the circuit, and 表 9-4 describes fault scenarios.

表 **9-4. Fault Scenarios and the Resulting V$_{OUT}$**

| FAULT SCENARIO | V$_{OUT}$ |
|---|---|
| V$_{CC}$ disconnects | Close to GND |
| GND disconnects | Close to V$_{CC}$ |
| V$_{CC}$ shorts to OUT | Close to V$_{CC}$ |
| GND shorts to OUT | Close to GND |

Product Folder Links: *TMAG5253*

English Data Sheet: *SBASAI5*

## 9.3 Best Design Practices

The Hall element is sensitive to magnetic fields that are perpendicular to the top of the package, therefore a correct magnet approach must be used for the sensor to detect the field. 图 9-11 shows correct and incorrect approaches.
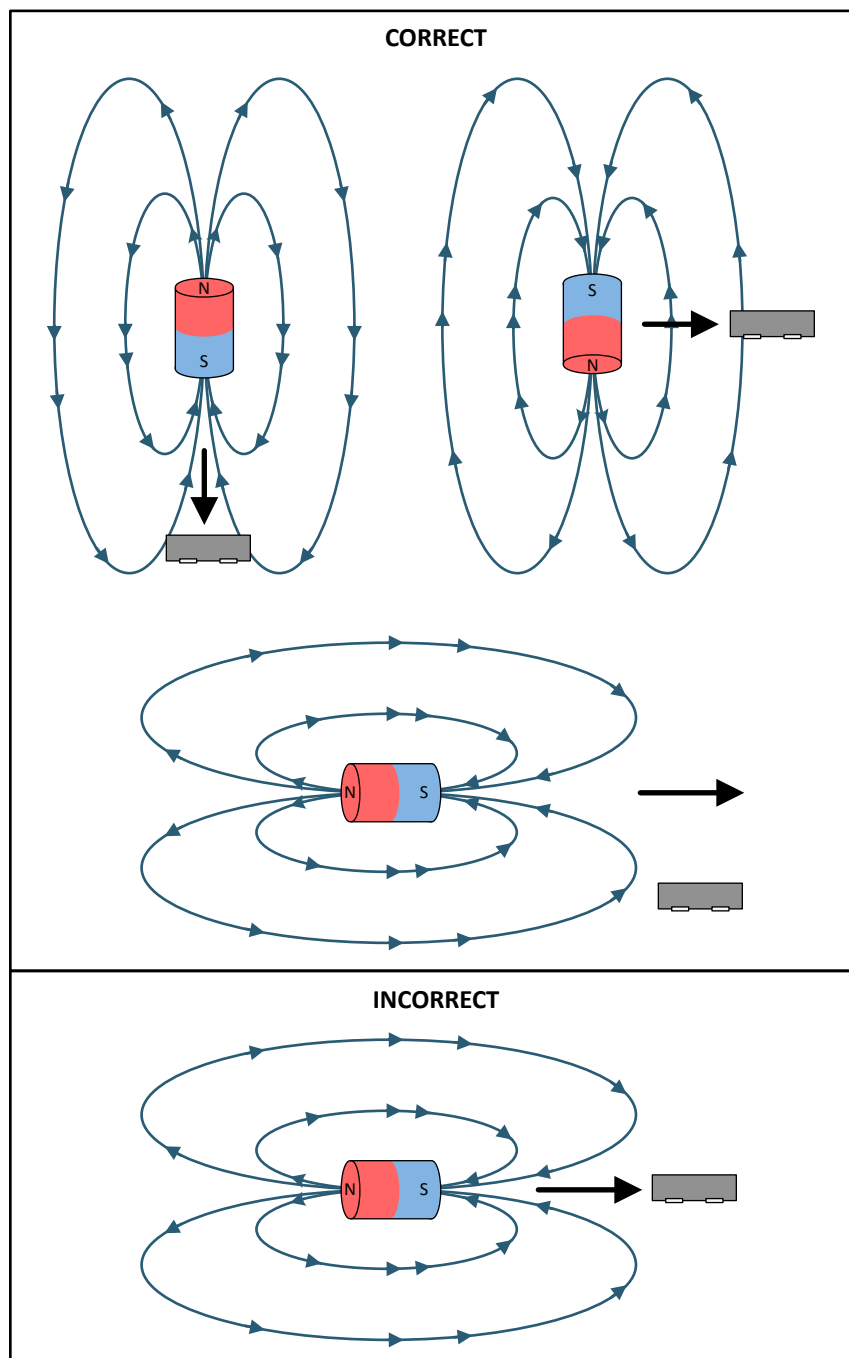


图 9-11. Correct and Incorrect Magnet Approaches

Product Folder Links: *TMAG5253*

English Data Sheet: SBASAI5

## 9.4 Power Supply Recommendations

A decoupling capacitor close to the device must be used to provide local energy with minimal inductance. TI recommends using a ceramic capacitor with a value of at least 0.1 μF.

## 9.5 Layout

### 9.5.1 Layout Guidelines

Magnetic fields pass through most nonferromagnetic materials with no significant disturbance. Embedding Hall effect sensors within plastic or aluminum enclosures and sensing magnets on the outside is common practice. Magnetic fields also easily pass through most printed circuit boards, which makes placing the magnet on the opposite side possible.

### 9.5.2 Layout Example



图 **9-12. Layout Example**

Product Folder Links: *TMAG5253*

English Data Sheet: SBASAI5
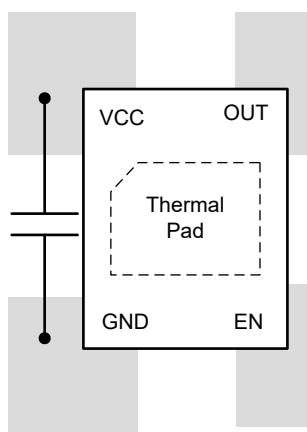
# 10 Device and Documentation Support

## 10.1 Documentation Support

### 10.1.1 Related Documentation

For related documentation see the following:

- Texas Instruments, *Absolute Angle Measurements for Rotational Motion Using Hall-Effect Sensors application brief*
- Texas Instruments, *Tracking Slide-By Displacement with Hall Effect Sensors* application brief
- Texas Instruments, *Head-on Linear Displacement Sensing using Hall Effect Sensors* application brief
- Texas Instruments, *TMAG5253EVM User's Guide*

## 10.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击*通知*进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

## 10.3 支持资源

TI E2E™ 中文支持论坛是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

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## 10.4 Trademarks

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## 10.5 静电放电警告

![ESD symbol]

静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

## 10.6 术语表

TI 术语表          本术语表列出并解释了术语、首字母缩略词和定义。

# 11 Revision History

注：以前版本的页码可能与当前版本的页码不同

| Changes from Revision * (May 2023) to Revision A (September 2023) | Page |
|---|---|
| • 将数据表状态从"预告信息"更改为："量产数据" ........................................................................ | 1 |

# 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type (2) | Package \| Pins | Package qty \| Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|---|---|---|---|---|---|---|---|---|---|
| TMAG5253BA1IQDMRR | Active | Production | X2SON (DMR) \| 4 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | BA1 |
| TMAG5253BA1IQDMRR.A | Active | Production | X2SON (DMR) \| 4 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | BA1 |
| TMAG5253BA2IQDMRR | Active | Production | X2SON (DMR) \| 4 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | BA2 |
| TMAG5253BA2IQDMRR.A | Active | Production | X2SON (DMR) \| 4 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | BA2 |
| TMAG5253BA3IQDMRR | Active | Production | X2SON (DMR) \| 4 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | BA3 |
| TMAG5253BA3IQDMRR.A | Active | Production | X2SON (DMR) \| 4 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | BA3 |
| TMAG5253BA4IQDMRR | Active | Production | X2SON (DMR) \| 4 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | BA4 |
| TMAG5253BA4IQDMRR.A | Active | Production | X2SON (DMR) \| 4 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | BA4 |

**(1)** **Status:** For more details on status, see our product life cycle.

**(2)** **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

**(3)** **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

**(4)** **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**(5)** **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

**(6)** **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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# PACKAGE MATERIALS INFORMATION

## TAPE AND REEL INFORMATION

**REEL DIMENSIONS**

**TAPE DIMENSIONS**

| A0 | Dimension designed to accommodate the component width |
|----|----|
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------|--------------|-----------------|------|-----|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TMAG5253BA1IQDMRR | X2SON | DMR | 4 | 3000 | 179.0 | 8.4 | 1.27 | 1.57 | 0.5 | 4.0 | 8.0 | Q1 |
| TMAG5253BA2IQDMRR | X2SON | DMR | 4 | 3000 | 179.0 | 8.4 | 1.27 | 1.57 | 0.5 | 4.0 | 8.0 | Q1 |
| TMAG5253BA3IQDMRR | X2SON | DMR | 4 | 3000 | 179.0 | 8.4 | 1.27 | 1.57 | 0.5 | 4.0 | 8.0 | Q1 |
| TMAG5253BA4IQDMRR | X2SON | DMR | 4 | 3000 | 179.0 | 8.4 | 1.27 | 1.57 | 0.5 | 4.0 | 8.0 | Q1 |

**TAPE AND REEL BOX DIMENSIONS**



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---|---|---|---|---|---|---|---|
| TMAG5253BA1IQDMRR | X2SON | DMR | 4 | 3000 | 200.0 | 183.0 | 25.0 |
| TMAG5253BA2IQDMRR | X2SON | DMR | 4 | 3000 | 200.0 | 183.0 | 25.0 |
| TMAG5253BA3IQDMRR | X2SON | DMR | 4 | 3000 | 200.0 | 183.0 | 25.0 |
| TMAG5253BA4IQDMRR | X2SON | DMR | 4 | 3000 | 200.0 | 183.0 | 25.0 |

This image is a representation of the package family, actual package may vary.
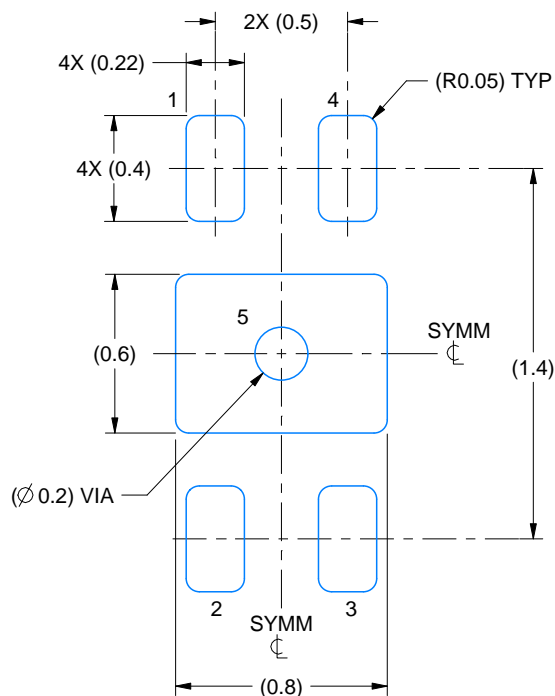Refer to the product data sheet for package details.

4229480/A

B

1.15
1.05

A

PIN 1 INDEX AREA

1.45
1.35

(0.13) TYP

C

0.4 MAX

SEATING PLANE

0.05
0.00

NOTE 4

⌒ 0.08 C

2X 0.5

SYMM
₵

2          3

NOTE 4

EXPOSED
THERMAL PAD

5

SYMM
₵

0.6±0.1

PIN 1 ID
(OPTIONAL)

4X 0.25
0.15

1          4

4X 0.27
0.17

0.8±0.1

⊕ | 0.1 Ⓜ | C | B Ⓢ | A Ⓢ |
| 0.05 Ⓜ | C |

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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.
4. Quantity and shape of side wall metal may vary.

2X (0.5)

4X (0.22)

1

4

(R0.05) TYP

4X (0.4)

5

(0.6)

SYMM
℄

(1.4)

(∅ 0.2) VIA

2

SYMM
℄

3

(0.8)

**LAND PATTERN EXAMPLE**
SCALE:35X

0.05 MAX
ALL AROUND

METAL

SOLDER MASK
OPENING

**NON SOLDER MASK
DEFINED
(PREFERRED)**

0.05 MIN
ALL AROUND

SOLDER MASK
OPENING

METAL UNDER
SOLDER MASK

**SOLDER MASK
DEFINED**
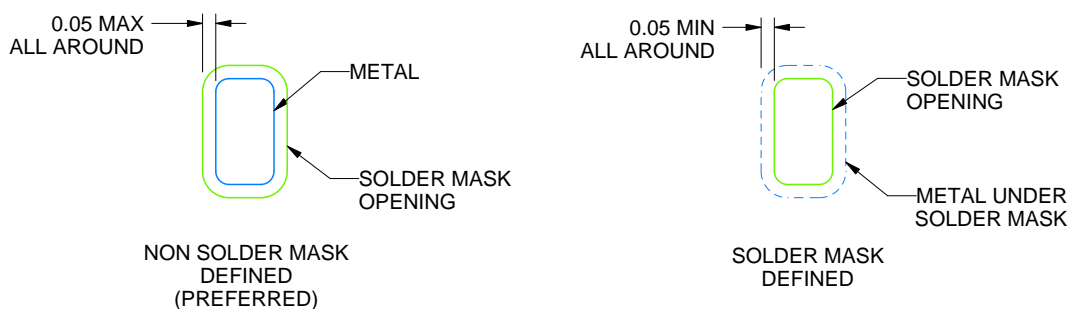
**SOLDER MASK DETAILS**

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NOTES: (continued)

5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature
   number SLUA271 (www.ti.com/lit/slua271).
6. Vias are optional depending on application, refer to device data sheet. If all or some are implemented, recommended via locations are shown.
   It is recommended that vias under paste be filled, plugged or tented.

2X (0.5)

4X (0.22)

1

4

(R0.05) TYP

4X (0.4)

5

(0.57)

SYMM ₵

(1.4)

METAL TYP

2

3

SYMM ₵

(0.76)
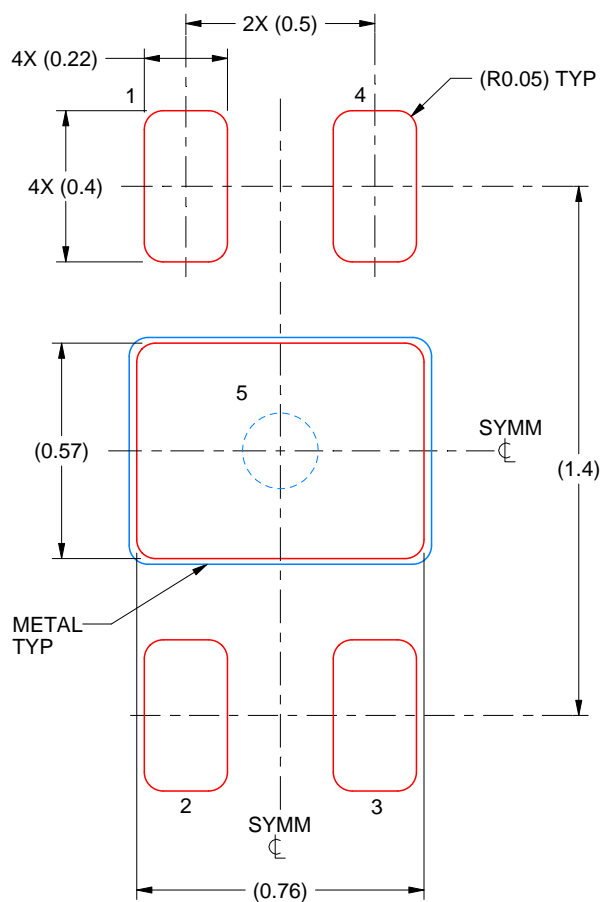
SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL

EXPOSED PAD 5:
90% PRINTED SOLDER COVERAGE BY AREA
SCALE:50X

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NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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